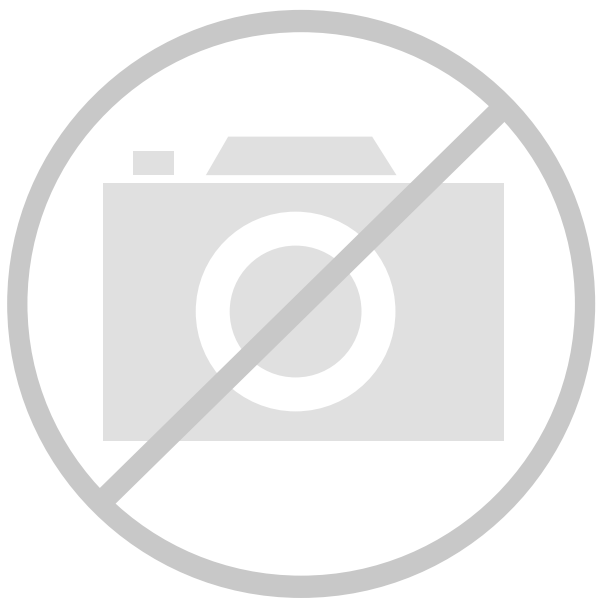




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Understanding [Embedded - Microprocessors](#)

Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

Applications of [Embedded - Microprocessors](#)

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

Details

Product Status	Active
Core Processor	ARM® Cortex®-A5 + Cortex®-M4
Number of Cores/Bus Width	2 Core, 32-Bit
Speed	400MHz, 167MHz
Co-Processors/DSP	Multimedia; NEON™ MPE
RAM Controllers	LPDDR2, DDR3, DRAM
Graphics Acceleration	Yes
Display & Interface Controllers	DCU, GPU, LCD, VideoADC, VIU
Ethernet	10/100Mbps (2)
SATA	-
USB	USB 2.0 OTG + PHY (1)
Voltage - I/O	3.3V
Operating Temperature	-40°C ~ 85°C (TA)
Security Features	ARM TZ, CAAM, HAB, RTIC, Secure JTAG, SNVS, Tamper, TZ ASC, TZ WDOG
Package / Case	364-LFBGA
Supplier Device Package	364-LFBGA (17x17)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/mvf60ns151cmk40

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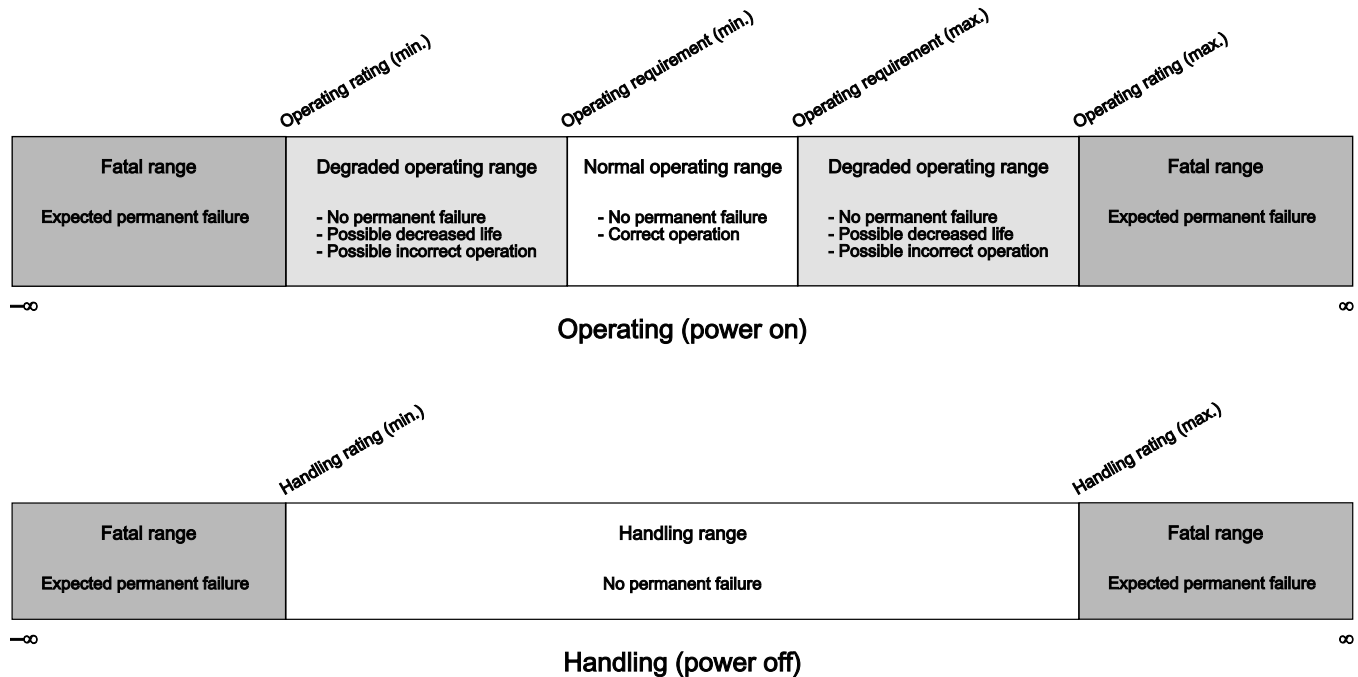
Field	Description	Values
R	Revision	1 = Rev 1.x
T	Temperature range (°C)	C = -40 °C to +85 °C T_a
PP	Package type	- KU = 176LQFP - MK = 364 MAPBGA
S	Speed	- Speed A5 Core 26 = 266MHz 40 = 400MHz 50 = 500MHz

2.4 Part Numbers

This table lists the part numbers on the device.

Part Number	Package	Description
MVF30NN151CKU26	LQFP-EP 176 24*24*1.6	A5-266, No Security, 176LQFP
MVF30NS151CKU26	LQFP-EP 176 24*24*1.6	A5-266, Security, 176LQFP
MVF50NN151CMK40	MAP 364 17*17*1.5 P0.8	A5-400, No Security, 364BGA
MVF50NS151CMK40	MAP 364 17*17*1.5 P0.8	A5-400, Security, 364BGA
MVF50NN151CMK50	MAP 364 17*17*1.5 P0.8	A5-500, No Security, 364BGA
MVF50NS151CMK50	MAP 364 17*17*1.5 P0.8	A5-500, Security, 364BGA
MVF51NN151CMK50	MAP 364 17*17*1.5 P0.8	A5-500, L2 Cache, No Security, 364BGA
MVF51NS151CMK50	MAP 364 17*17*1.5 P0.8	A5-500, L2 Cache, Security, 364BGA
MVF60NN151CMK40	MAP 364 17*17*1.5 P0.8	A5-400, M4, No Security, 364BGA
MVF60NS151CMK40	MAP 364 17*17*1.5 P0.8	A5-400, M4, Security, 364BGA
MVF60NN151CMK50	MAP 364 17*17*1.5 P0.8	A5-500, M4, No Security, 364BGA
MVF60NS151CMK50	MAP 364 17*17*1.5 P0.8	A5-500, M4, Security, 364BGA
MVF61NN151CMK50	MAP 364 17*17*1.5 P0.8	A5-500, M4, L2 Cache, No Security, 364BGA
MVF61NS151CMK50	MAP 364 17*17*1.5 P0.8	A5-500, M4, L2 Cache, Security, 364BGA
MVF62NN151CMK40	MAP 364 17*17*1.5 P0.8	A5-400, M4 Primary, No Security, 364BGA

3.6 Relationship between ratings and operating requirements



3.7 Guidelines for ratings and operating requirements

Follow these guidelines for ratings and operating requirements:

- Never exceed any of the chip's ratings.
- During normal operation, don't exceed any of the chip's operating requirements.
- If you must exceed an operating requirement at times other than during normal operation (for example, during power sequencing), limit the duration as much as possible.

3.8 Definition: Typical value

A *typical value* is a specified value for a technical characteristic that:

- Lies within the range of values specified by the operating behavior
- Given the typical manufacturing process, is representative of that characteristic during operation when you meet the typical-value conditions or other specified conditions

Typical values are provided as design guidelines and are neither tested nor guaranteed.

6.2 Nonswitching electrical specifications

6.2.1 VREG electrical specifications

6.2.1.1 HPREG electrical characteristics

Table 2. HPREG electrical characteristics

Parameters	Min	Typ	Max	Unit	Comments
Power supply	3.0	3.3	3.6	V	-
Current Consumption	-	1.2	1.5	mA	@ no load
	-	2.0	2.5	mA	@ full load
Output current capacity	-	600	1200 ¹	mA	DC load current
Output voltage @ no load		1.23	1.26	V	
Output voltage @ full load	1.20	1.21		V	
External decoupling cap	4.7		-	μF	-
	0.05		0.1	Ohms	ESR of external cap
			20	mOhms	Total effective PAD+PCB trace resistances
PSRR with 4.7μF output cap					
@ DC @noload			-48	dB	
@ DC @full load			-40		
@ worst case any frequency			-20		

1. This is peak and not continuous maximum value.

6.2.1.2 LPREG electrical characteristics

Table 3. LPREG electrical characteristics

Parameters	Min	Typ	Max	Unit	Comments
Power supply	3.0	3.3	3.6	V	
Current Consumption	350	400		μA	@ no load
	-	500	650	μA	@ full load
Output current capacity		100	200	mA	DC load current
Output voltage @ no load		1.22	1.240	V	
Output voltage @ full load	1.180			V	
External decoupling cap	4.7			μF	
	0.05		0.1	Ohms	ESR of external cap
			20	mOhms	Total PAD+PCB trace resistance

Table continues on the next page...

6.2.2 LVD electrical specifications

6.2.2.1 Main Supply electrical characteristics

Table 9. LVD_MAIN supply electrical characteristics

Main Supply LVD Parameters	Min	Typ	Max	Unit	Comments
Power supply	3.0	3.3	3.6	V	
Upper voltage threshold (value @27°C)		2.76	2.915	V	
Lower voltage threshold (value @27°C)	2.656	2.73		V	
Time constant of RC filter at LVD input (0.69*RC)	3.3			μs	3.3 V noise rejection at LVD comparator input

6.2.2.2 LVD DIG characteristics

Table 10. LVD DIG electrical specifications [HPREG(RUN MODE) and LPREG(STOP MODE)]

LVD DIG Parameters	Min	Typ	Max	Unit	Comments
Power supply	3.0	3.3	3.6	V	
Upper voltage threshold	1.135	1.16	1.185	V	
Lower voltage threshold	1.105	1.13	1.155	V	
Time constant of RC filter at LVD input	200			ns	1.2V noise rejection at the input of LVD comparator

Table 11. LVD DIG electrical specifications [ULPREG(STANDBY MODE)]

LVD DIG Parameters	Min	Typ	Max	Unit	Comments
Power supply	3.0	3.3	3.6	V	
Upper voltage threshold	1.105	1.13	1.155	V	
Lower voltage threshold	1.075	1.10	1.125	V	
Time constant of RC filter at LVD input	200			ns	1.2V noise rejection at the input of LVD comparator

Table 24. LPDDR2 mode DC Electrical characteristics (continued)

Symbol	Parameter	Test condition	Min	Typ	Max	Unit	Notes
I_{in}^2	Input current (no pull-up/down)	$V_{in} = ovdd$ or 0			2.5	uA	
Tri-state I/O supply current ²	$I_{cc-ovdd}$	$V_{in} = ovdd$ or 0			4		
Tri-state vdd2p5 supply current ²	$I_{cc-vdd2p5}$	$V_i = vddi$ or 0			1.5		
Tri-state core supply current ²	$I_{cc-vddi}$				1		
Driver unit (240 Ohm) calibration resolution	Rres				10	Ohm	

1. The single-ended signals need to be within the respective limits ($V_{ih}(dc)$ max, $V_{il}(dc)$ min) for single-ended signals as well as the limitations for overshoot and undershoot.
2. Typ condition: typ model, 1.2 V, and 25 °C junction. Max condition: bcs model, 1.26V, and -40 °C. Min condition: wcs model, 1.14V, and T_j 125 °C.

Table 25. DDR3 mode DC Electrical characteristics

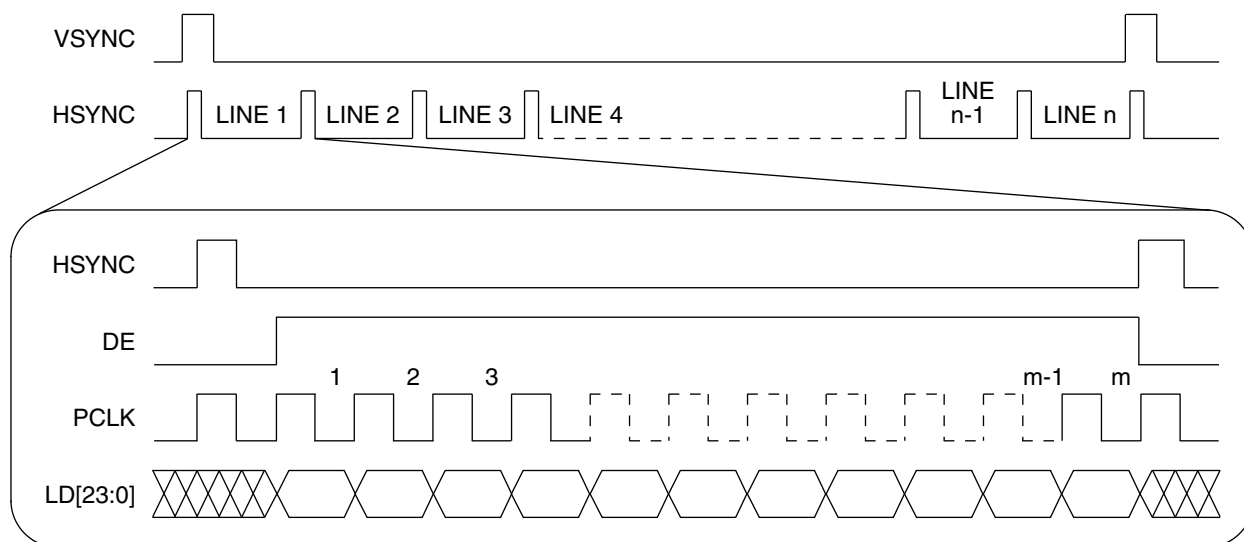
Symbol	Parameter	Test condition	Min	Typ	Max	Unit	Notes
V_{oh}	High-level output voltage		$0.8 \cdot ovdd$			V	Note that the JEDEC JESD79_3E specification supersedes any specification in this document
V_{ol}	Low-level output voltage	$I_{ol} = 1mA$			$0.2 \cdot ovdd$	V	
V_{ref}	Input reference voltage		$0.49 \cdot ovdd$	$0.5 \cdot ovdd$	$0.51 \cdot ovdd$	V	
$V_{ih}(dc)$	DC input high voltage		$V_{ref} + 0.1$		$ovdd$	V	
$V_{il}(dc)$	DC input low voltage		$ovss$		$V_{ref} - 0.1$	V	
$V_{ih}(diff)$	DC differential input logic high		0.2		Note ¹	V	
$V_{il}(diff)$	DC differential input logic low		Note ¹		-0.2	V	
V_{tt}^2	Termination voltage	$V_{in} = ovdd$ or 0	$0.49 \cdot ovdd$	$0.5 \cdot ovdd$	$0.51 \cdot ovdd$		
I_{in}^3	Input current (no pullup/pulldown)	$V_i = 0$ $V_i = ovdd$			3	uA	

Table continues on the next page...

Table 32. 12-bit ADC Characteristics ($V_{REFH} = V_{DDAD}$, $V_{REFL} = V_{SSAD}$) (continued)

Characteristic	Conditions ¹	Symb	Min	Typ ²	Max	Unit	Comment
	ADLSMP=0 ADSTS=10			0.8			
	ADLSMP=0 ADSTS=11			0.85			
	ADLSMP=1 ADSTS=00			0.95			
	ADLSMP=1 ADSTS=01			1.05			
	ADLSMP=1 ADSTS=10			1.15			
	ADLSMP=1, ADSTS=11			1.25			
Total Unadjusted Error	12 bit mode	TUE	-2	-	+5	LSB ³	With Max Averaging
	10 bit mode		-0.5	-	+2		
	8 bit mode		-0.25	-	+1.5		
Differential Non-Linearity	12 bit mode	DNL	-	±0.6	±1.5	LSB ³	Waiting for histogram method confirmation
	10bit mode		-	±0.5	±1		
	8 bit mode		-	±0.25	±0.5		
Integral Non-Linearity	12 bit mode	INL	-	±2	±4	LSB ³	Waiting for histogram method confirmation
	10bit mode		-	±1	±2		
	8 bit mode		-	±0.5	±1		
Zero-Scale Error	12 bit mode	E _{ZS}	-	+1.0	±1.6	LSB ³	VADIN = V _{REFL} With Max Averaging
	10bit mode		-	±0.4	±0.8		
	8 bit mode		-	±0.1	±0.4		
Full-Scale Error	12 bit mode	E _{FS}	-	±2	±3.5	LSB ³	VADIN = V _{REFH} With Max Averaging
	10bit mode		-	±0.5	±1		
	8 bit mode		-	±0.25	±0.75		
Quantization Error	12 bit mode	E _Q	-	±1 to 0		LSB ³	
	10bit mode		-	±0.5			
	8 bit mode		-	±0.5			
Effective Number of Bits	12 bit mode	ENOB	10.1	10.7	-	Bits	Fin = 100Hz
Signal to Noise plus Distortion	See ENOB	SINAD	SINAD = 6.02 x ENOB + 1.76			dB	
Input Leakage Error	all modes	EIL	I _{in} x RAS			mV	I _{in} = 400 nA leakage current
Temp Sensor Slope	Across the full temperature range of the device	m	--	1.84	--	mV/°C	
Temp Sensor Voltage	25°C	V _{TEMP25}	-	696	-	mV	

1. All accuracy numbers assume the ADC is calibrated with $V_{REFH}=V_{DDAD}$
2. Typical values assume $V_{DDAD} = 3.0$ V, Temp = 25°C, $F_{adck}=20$ MHz unless otherwise stated. Typical values are for reference only and are not tested in production.
3. 1 LSB = $(V_{REFH} - V_{REFL})/2N$



9.2.1.2 Interface to TFT LCD Panels—Pixel Level Timings

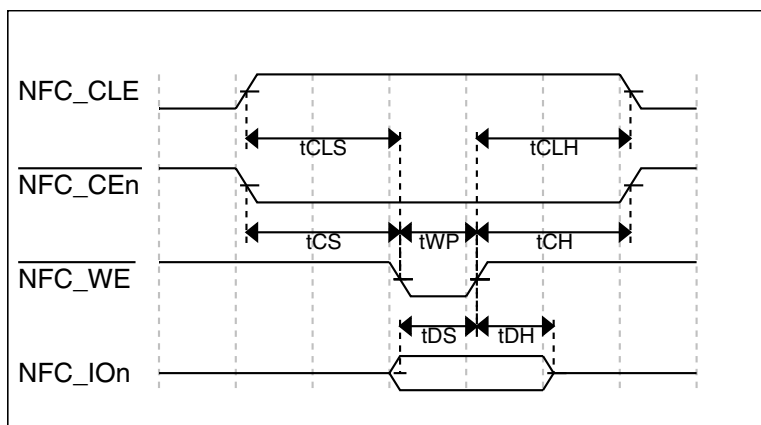
This section provides the horizontal timing (timing of one line), including both the horizontal sync pulse and data. All parameters shown in the figure below are programmable. This timing diagram corresponds to positive polarity of the PCLK signal (meaning the data and sync signals change on the rising edge) and active-high polarity of the HSYNC, VSYNC and DE signals. The user can select the polarity of the HSYNC and VSYNC signals via the SYN_POL register, whether active-high or active-low. The default is active-high. The DE signal is always active-high. Pixel clock inversion and a flexible programmable pixel clock delay are also supported. They are programmed via the clock divide . The DELTA_X and DELTA_Y parameters are programmed via the DISP_SIZE register. The PW_H, BP_H and FP_H parameters are programmed via the HSYN PARA register. The PW_V, BP_V and FP_V parameters are programmed via the VSYN_PARA register.

Table 36. LCD interface timing parameters—horizontal and vertical

Symbol	Characteristic		Unit
t_{PCP}	Display pixel clock period	11.2	ns
t_{PWH}	HSYNC pulse width	$PW_H * t_{PCP}$	ns
t_{BPH}	HSYNC back porch width	$BP_H * t_{PCP}$	ns
t_{FPH}	HSYNC front porch width	$FP_H * t_{PCP}$	ns
t_{SW}	Screen width	$DELTA_X * t_{PCP}$	ns
t_{HSP}	HSYNC (line) period	$(PW_H + BP_H + FP_H + DELTA_X) * t_{PCP}$	ns
t_{PWV}	VSYNC pulse width	$PW_V * t_{HSP}$	ns
t_{BPV}	VSYNC back porch width	$BP_V * t_{HSP}$	ns
t_{FPV}	VSYNC front porch width	$FP_V * t_{HSP}$	ns
t_{SH}	Screen height	$DELTA_Y * t_{HSP}$	ns
t_{VSP}	VSYNC (frame) period	$(PW_V + BP_V + FP_V + DELTA_Y) * t_{HSP}$	ns

Table 52. NFC specifications

Num	Description	Min.	Max.	Unit
t_{CLS}	NFC_CLE setup time	$2T_H + T_L - 1$	—	ns
t_{CLH}	NFC_CLE hold time	$T_H + T_L - 1$	—	ns
t_{CS}	$\overline{\text{NFC_CEn}}$ setup time	$2T_H + T_L - 1$	—	ns
t_{CH}	$\overline{\text{NFC_CEn}}$ hold time	$T_H + T_L$	—	ns
t_{WP}	$\overline{\text{NFC_WP}}$ pulse width	$T_L - 1$	—	ns
t_{ALS}	NFC_ALE setup time	$2T_H + T_L$	—	ns
t_{ALH}	NFC_ALE hold time	$T_H + T_L$	—	ns
t_{DS}	Data setup time	$T_L - 1$	—	ns
t_{DH}	Data hold time	$T_H - 1$	—	ns
t_{WC}	Write cycle time	$T_H + T_L - 1$	—	ns
t_{WH}	$\overline{\text{NFC_WE}}$ hold time	$T_H - 1$	—	ns
t_{RR}	Ready to $\overline{\text{NFC_RE}}$ low	$4T_H + 3T_L + 90$	—	ns
t_{RP}	$\overline{\text{NFC_RE}}$ pulse width	$T_L + 1$	—	ns
t_{RC}	Read cycle time	$T_L + T_H - 1$	—	ns
t_{REH}	$\overline{\text{NFC_RE}}$ high hold time	$T_H - 1$	—	ns
t_{IS}	Data input setup time	11	—	ns


Figure 34. Command latch cycle timing

NOTE

Measurements were done using balanced load and 25 ohms resistor from outputs to VDD_REF.

9.5.4.5 LPDDR2 Read Cycle

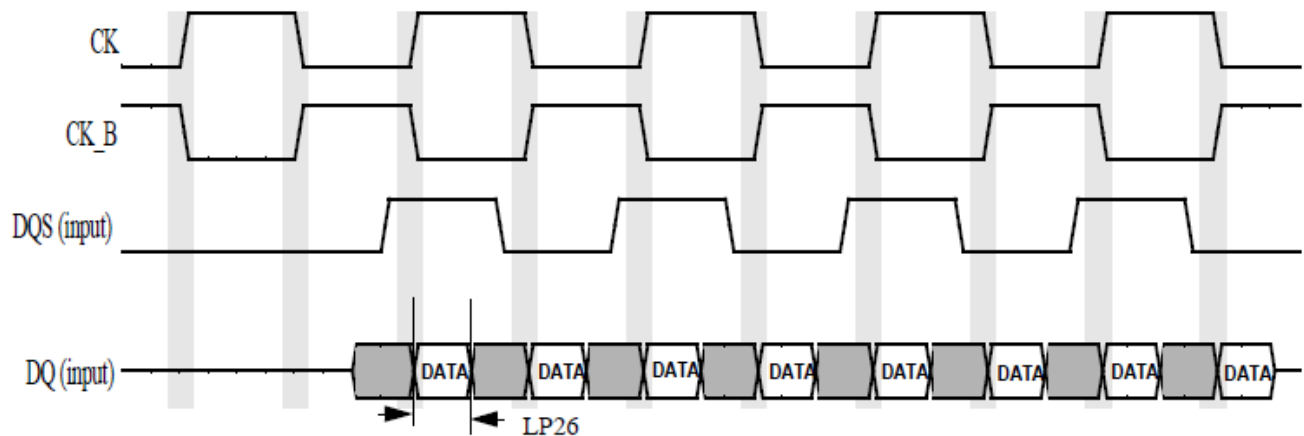


Figure 45. LPDDR2 Read cycle

Table 58. LPDDR2 Read Cycle

ID	Parameter	Symbol	CK = 400 MHz		Unit
			Min	Max	
LP26	Minimum required DQ valid window width for LPDDR2	-	270	-	ps

NOTE

To receive the reported setup and hold values, read calibration should be performed in order to locate the DQS in the middle of DQ window.

NOTE

All measurements are in reference to Vref level.

NOTE

Measurements were done using balanced load and 25 ohms resistor from outputs to VDD_REF

9.7 Clocks and PLL Specifications

9.7.1 24 MHz Oscillator Specifications

The system crystal oscillator consists of a Pierce-type structure running off the digital supply. A straight forward biased-inverter implementation is used. The crystal must be rated for a drive level of 250 μ W or higher. An ESR (equivalent series resistance) of 80 Ω or less is recommended to achieve a gain margin of 5.

Table 64. 24MHz external oscillator electrical characteristics

Symbol	Parameter	Condition	Value			Unit
			Min	Typ	Max	
f_{osc}	Crystal oscillator range	—	—	24	—	MHz
I_{osc}	Startup current	—	—	< 5	—	mA
t_{uposc}	Oscillator startup time	—	—	< 5	—	ms
C_{IN}	Input Capacitance	EXTAL and XTAL pins	—	9	—	pF
V_{IH}	XTAL pin input high voltage	—	0.8 x V_{DD}^1	—	$V_{DD} + 0.3$	V
V_{IL}	XTAL pin input low voltage	—	$V_{SS} - 0.3$	—	0.2 x V_{DD}	V

1. $V_{DD} = 1.1 \text{ V} \pm 10\%$, $T_A = -40$ to $+85^\circ\text{C}$, unless otherwise specified.

9.7.2 32 KHz Oscillator Specifications

This block implements an amplifier that when combined with a suitable quartz crystal and external load capacitors implements a low power oscillator. It also implements a power mux such that it can be powered from either a $\sim 3 \text{ V}$ backup battery or VDDIO such as the oscillator consumes power from VDDIO when that supply is available and transitions to the back up battery when VDDIO is lost.

In addition, if the clock monitor determines that the OSC32K is not present, then the source of the 32 K will automatically switch to the 128kHz internal RC clock divided by 4.

The OSC32k runs from vdd_rtc supply, generated inside OSC32k itself from VDDIO/ VBAT. The target battery is a $\sim 3 \text{ V}$ coin cell. Proper choice of coin cell type is necessary for chosen VDDIO range. Appropriate series resistor (R_s) must be used when connecting the coin cell. R_s depends on the charge current limit that depends on the chosen coin cell.

For example:

9.7.6 PLL3 and PLL7 (480 MHz USB PLL) Electrical Parameters

Table 69. PLL3 and PLL7 Electrical Parameters

Parameter	Value
Clock output range	480 MHz PLL output
Reference clock	24 MHz
Lock time	<425 reference cycles
Period jitter(p2p)	<140 ps
Duty Cycle	48.9%~51.7% PLL output

9.7.7 PLL5 (Ethernet PLL) Electrical Parameters

Table 70. PLL5 Electrical Parameters

Parameter	Value
Clock output range	500 MHz
Reference clock	24 MHz
Lock time	<7500 reference cycles
Cycle to cycle jitter (p2p) ¹	<400ps @ 50 MHz
Duty Cycle	45%~55%

1. Jitter numbers are measured at divided PLL clock because high frequency cannot be brought-out IO pad.

9.7.8 PLL4 (Audio PLL) Electrical Parameters

Table 71. PLL4 Electrical Parameters

Parameter	Value
Clock output range	650 MHz ~1.3 GHz
Reference clock	24 MHz
Lock time	<7500 reference cycles
Long term jitter(RMS)	<42ps @ 1128MHz
Period jitter(p2p) ¹	<115ps@1128MHz
Duty Cycle	43%~57%

1. Jitter numbers are measured at divided PLL clock because high frequency cannot be brought-out on IO pad.

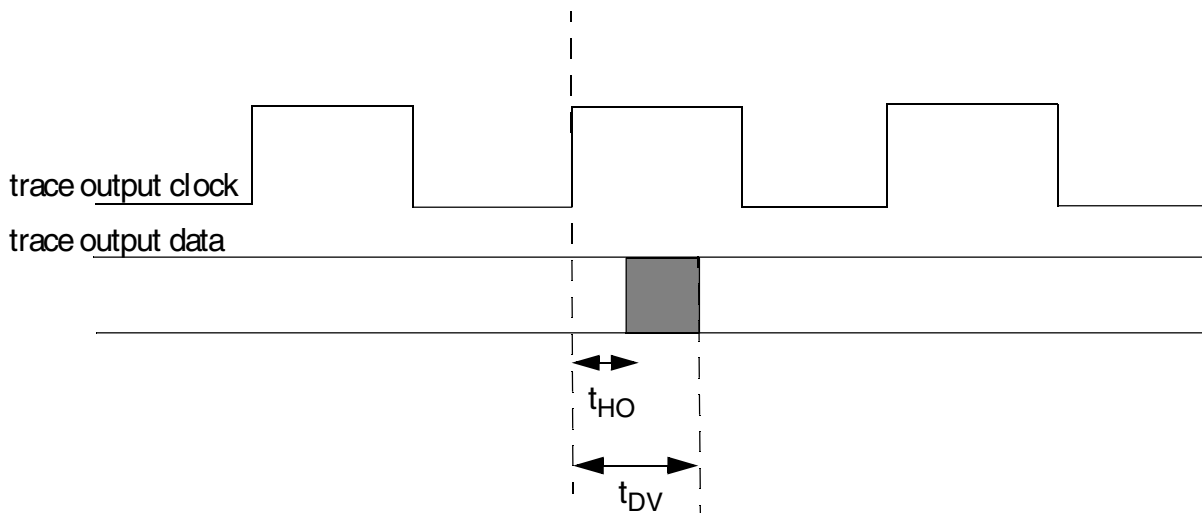


Figure 57. Trace data specifications

10 Thermal attributes

10.1 Thermal attributes

Board type	Symbol	Description	176LQFP	Unit	Notes
Single-layer (1s)	$R_{\theta JA}$	Thermal resistance, junction to ambient (natural convection)	50	$^{\circ}\text{C}/\text{W}$	1, 2
Four-layer (2s2p)	$R_{\theta JA}$	Thermal resistance, junction to ambient (natural convection)	32	$^{\circ}\text{C}/\text{W}$	1,3
Single-layer (1s)	$R_{\theta JMA}$	Thermal resistance, junction to ambient (200 ft./min. air speed)	40	$^{\circ}\text{C}/\text{W}$	1, 3
Four-layer (2s2p)	$R_{\theta JMA}$	Thermal resistance, junction to ambient (200 ft./min. air speed)	25	$^{\circ}\text{C}/\text{W}$	1, 3
—	$R_{\theta JB}$	Thermal resistance, junction to board	21	$^{\circ}\text{C}/\text{W}$	4
—	$R_{\theta J\text{Ctop}}$	Thermal resistance, junction to case top	12	$^{\circ}\text{C}/\text{W}$	5
—	Ψ_{JT}	Thermal characterization parameter, junction	3	$^{\circ}\text{C}/\text{W}$	6

364 MAP BGA	176 LQFP	Pin Name	Default	ALT0	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7	EzPort
V1	38	VDDA33_ ADC			VDDA33_ ADC							
V2	39	VSSA33_ ADC			VSSA33_ ADC							
U1	36	DACO0			DACO0							
U2	37	DACO1			DACO1							
Y4	—	VADCSE0			VADCSE0							
U4	—	VADCSE1			VADCSE1							
W4	—	VADCSE2			VADCSE2							
V5	—	VADCSE3			VADCSE3							
V3	—	VDDA33_ AFE			VDDA33_ AFE							
V4	—	VSSA33_AFE			VSSA33_AFE							
T5	—	VDD12_AFE			VDD12_AFE							
R5	—	VSS12_AFE			VSS12_AFE							
U5	—	VADC_AFE_ BANDGAP			VADC_AFE_ BANDGAP							
Y13	73	EXTAL			EXTAL							
W13	72	XTAL			XTAL							
Y12	70	EXTAL32			EXTAL32							
W12	71	XTAL32			XTAL32							
T4	35	RESETB/ RESET_OUT	RESETB/ RESET_OUT		RESETB/ RESET_OUT							
N5	19	PTA6		PTA6	RMII_ CLKOUT	RMII_CLKIN/ MII0_TXCLK		DCU1_ TCON11			DCU1_R2	
T3	34	TEST			TEST							
T1	30	Ext_POR			TEST2							
V12	69	DECAP_ V11_LDO_ OUT			DECAP_ V11_LDO_ OUT							
T11	65	DECAP_ V25_LDO_ OUT			DECAP_ V25_LDO_ OUT							
T2	33	BCTRL			BCTRL							
P5	31	VDDREG			VDDREG							
T12	68	VDD33_ LDON			VDD33_ LDON							
V11	67	VSS			VSS							
U11	66	VSS_KE0			VSS_KE0							
W14	—	LVDS0P			LVDS0P							
Y14	—	LVDS0N			LVDS0N							
K4	3	JTCLK/ SWCLK	JTCLK/ SWCLK	PTA8	JTCLK/ SWCLK			DCU0_R0			MLBCLK	

364 MAP BGA	176 LQFP	Pin Name	Default	ALT0	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7	EzPort
A10	—	DDR_A[13]			DDR_A13							
C10	—	DDR_A[12]			DDR_A12							
D10	—	DDR_A[11]			DDR_A11							
D7	—	DDR_A[10]			DDR_A10							
B9	—	DDR_A[9]			DDR_A9							
A11	—	DDR_A[8]			DDR_A8							
A7	—	DDR_A[7]			DDR_A7							
A9	—	DDR_A[6]			DDR_A6							
B6	—	DDR_A[5]			DDR_A5							
A6	—	DDR_A[4]			DDR_A4							
B7	—	DDR_A[3]			DDR_A3							
A8	—	DDR_A[2]			DDR_A2							
C11	—	DDR_A[1]			DDR_A1							
C7	—	DDR_A[0]			DDR_A0							
D8	—	DDR_BA[2]			DDR_BA2							
C9	—	DDR_BA[1]			DDR_BA1							
C8	—	DDR_BA[0]			DDR_BA0							
B4	—	DDR_CAS_b			DDR_CAS_b							
A5	—	DDR_CKE[0]			DDR_CKE0							
A2	—	DDR_CLK[0]			DDR_CLK0							
B2	—	DDR_CLK_b[0]			DDR_CLK_b0							
C5	—	DDR_CS_b[0]			DDR_CS_b0							
D2	—	DDR_D[15]			DDR_D15							
H2	—	DDR_D[14]			DDR_D14							
C1	—	DDR_D[13]			DDR_D13							
G1	—	DDR_D[12]			DDR_D12							
E2	—	DDR_D[11]			DDR_D11							
H1	—	DDR_D[10]			DDR_D10							
D1	—	DDR_D[9]			DDR_D9							
J1	—	DDR_D[8]			DDR_D8							
G3	—	DDR_D[7]			DDR_D7							
C3	—	DDR_D[6]			DDR_D6							
J3	—	DDR_D[5]			DDR_D5							
F3	—	DDR_D[4]			DDR_D4							
G4	—	DDR_D[3]			DDR_D3							
D4	—	DDR_D[2]			DDR_D2							
H3	—	DDR_D[1]			DDR_D1							
F4	—	DDR_D[0]			DDR_D0							
G2	—	DDR_DQM[1]			DDR_DQM1							

364 MAP BGA	176 LQFP	Pin Name	Default	ALT0	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7	EzPort
E4	—	SDRAMC_ VDD1P5			SDRAMC_ VDD1P5							
D5	—	SDRAMC_ VDD1P5			SDRAMC_ VDD1P5							
F5	—	SDRAMC_ VDD1P5			SDRAMC_ VDD1P5							
H5	—	SDRAMC_ VDD1P5			SDRAMC_ VDD1P5							
K5	—	SDRAMC_ VDD1P5			SDRAMC_ VDD1P5							
E7	—	SDRAMC_ VDD1P5			SDRAMC_ VDD1P5							
E9	—	SDRAMC_ VDD1P5			SDRAMC_ VDD1P5							
D11	—	SDRAMC_ VDD1P5			SDRAMC_ VDD1P5							
K3	10	VDD33			VDD33							
N3	25	VDD33			VDD33							
V8	52	VDD33			VDD33							
C12	83	VDD33			VDD33							
C15	—	VDD33			VDD33							
U16	95	VDD33			VDD33							
K17	108	VDD33			VDD33							
N17	127	VDD33			VDD33							
T17	140	VDD33			VDD33							
C18	146	VDD33			VDD33							
F18	158	VDD33			VDD33							
W18	168	VDD33			VDD33							
H7	—	VSS			VSS							
K7	45	VSS			VSS							
M7	82	VSS			VSS							
P7	—	VSS			VSS							
G8	96	VSS			VSS							
J8	107	VSS			VSS							
L8	—	VSS			VSS							
N8	139	VSS			VSS							
H9	144	VSS			VSS							
J9	157	VSS			VSS							
K9	175	VSS			VSS							
L9	176	VSS			VSS							
M9	—	VSS			VSS							
P9	—	VSS			VSS							
G10	—	VSS			VSS							

Pinouts

364 MAP BGA	176 LQFP	Pin Name	Default	ALT0	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7	EzPort
J10	—	VSS			VSS							
K10	—	VSS			VSS							
L10	—	VSS			VSS							
M10	—	VSS			VSS							
N10	—	VSS			VSS							
H11	—	VSS			VSS							
J11	—	VSS			VSS							
K11	—	VSS			VSS							
L11	—	VSS			VSS							
M11	—	VSS			VSS							
P11	—	VSS			VSS							
G12	—	VSS			VSS							
J12	—	VSS			VSS							
K12	—	VSS			VSS							
L12	—	VSS			VSS							
M12	—	VSS			VSS							
N12	—	VSS			VSS							
H13	—	VSS			VSS							
K13	—	VSS			VSS							
M13	—	VSS			VSS							
P13	—	VSS			VSS							
G14	—	VSS			VSS							
J14	—	VSS			VSS							
L14	—	VSS			VSS							
N14	—	VSS			VSS							
N7	—	FA_VDD			FA_VDD							
V14	75	VBAT			VBAT							
—	FLG	VSS			VSS							

12.2 Pinout diagrams

NOTE

The 176 LQFP parts are not pin compatible between the F and R series families devices.

NOTE

If tamper detection is not required, the tamper pins must be tied to ground.

Table 75. RGPIO versus Pins (continued)

RGPIO	In GPIO module	Corresponding Pin on the chip	IOMUX register name	IOMUX register address
RGPIO[40]	PORT1[8]	PTB18	IOMUXC_PTB18	400480A0
RGPIO[41]	PORT1[9]	PTB19	IOMUXC_PTB19	400480A4
RGPIO[42]	PORT1[10]	PTB20	IOMUXC_PTB20	400480A8
RGPIO[43]	PORT1[11]	PTB21	IOMUXC_PTB21	400480AC
RGPIO[44]	PORT1[12]	PTB22	IOMUXC_PTB22	400480B0
RGPIO[45]	PORT1[13]	PTC0	IOMUXC_PTC0	400480B4
RGPIO[46]	PORT1[14]	PTC1	IOMUXC_PTC1	400480B8
RGPIO[47]	PORT1[15]	PTC2	IOMUXC_PTC2	400480BC
RGPIO[48]	PORT1[16]	PTC3	IOMUXC_PTC3	400480C0
RGPIO[49]	PORT1[17]	PTC4	IOMUXC_PTC4	400480C4
RGPIO[50]	PORT1[18]	PTC5	IOMUXC_PTC5	400480C8
RGPIO[51]	PORT1[19]	PTC6	IOMUXC_PTC6	400480CC
RGPIO[52]	PORT1[20]	PTC7	IOMUXC_PTC7	400480D0
RGPIO[53]	PORT1[21]	PTC8	IOMUXC_PTC8	400480D4
RGPIO[54]	PORT1[22]	PTC9	IOMUXC_PTC9	400480D8
RGPIO[55]	PORT1[23]	PTC10	IOMUXC_PTC10	400480DC
RGPIO[56]	PORT1[24]	PTC11	IOMUXC_PTC11	400480E0
RGPIO[57]	PORT1[25]	PTC12	IOMUXC_PTC12	400480E4
RGPIO[58]	PORT1[26]	PTC13	IOMUXC_PTC13	400480E8
RGPIO[59]	PORT1[27]	PTC14	IOMUXC_PTC14	400480EC
RGPIO[60]	PORT1[28]	PTC15	IOMUXC_PTC15	400480F0
RGPIO[61]	PORT1[29]	PTC16	IOMUXC_PTC16	400480F4
RGPIO[62]	PORT1[30]	PTC17	IOMUXC_PTC17	400480F8
RGPIO[63]	PORT1[31]	PTD31	IOMUXC_PTD31	400480FC
RGPIO[64]	PORT2[0]	PTD30	IOMUXC_PTD30	40048100
RGPIO[65]	PORT2[1]	PTD29	IOMUXC_PTD29	40048104
RGPIO[66]	PORT2[2]	PTD28	IOMUXC_PTD28	40048108
RGPIO[67]	PORT2[3]	PTD27	IOMUXC_PTD27	4004810C
RGPIO[68]	PORT2[4]	PTD26	IOMUXC_PTD26	40048110
RGPIO[69]	PORT2[5]	PTD25	IOMUXC_PTD25	40048114
RGPIO[70]	PORT2[6]	PTD24	IOMUXC_PTD24	40048118
RGPIO[71]	PORT2[7]	PTD23	IOMUXC_PTD23	4004811C
RGPIO[72]	PORT2[8]	PTD22	IOMUXC_PTD22	40048120
RGPIO[73]	PORT2[9]	PTD21	IOMUXC_PTD21	40048124
RGPIO[74]	PORT2[10]	PTD20	IOMUXC_PTD20	40048128
RGPIO[75]	PORT2[11]	PTD19	IOMUXC_PTD19	4004812C
RGPIO[76]	PORT2[12]	PTD18	IOMUXC_PTD18	40048130
RGPIO[77]	PORT2[13]	PTD17	IOMUXC_PTD17	40048134
RGPIO[78]	PORT2[14]	PTD16	IOMUXC_PTD16	40048138

Table continues on the next page...

Table 79. Revision History (continued)

Rev. No.	Date	Substantial Changes
		Updated Power supply diagram Updated AC electrical specification of following modules: DCU, 12-bit DAC, Ethernet, Enhanced Serial Audio Interface (ESAI), SAI/I2S, Flexbus, MLB, DSPI, 24MHz External Oscillator, JTAG, Debug, ESAI, QSPI Updated Thermal Attributes for 364 MAPBGA Updated Freescale document number for 176-pin LQFP and 364 MAPBGA Updated VREG specifications Added WBREG specifications Updated Recommended operating conditions table Updated DAC INL and DNL charts Updated Pinouts
Rev 4.1	12/2012	Editorial updates: Removed instances of VF7xx and VF4xx.
Rev 5	April 2013	- Removed references to VF1xxR and references to F100 and 144 LQFP and 256 MAPBGA - Replaced references to Auto and IMM by R-series and F-series respectively - In the feature list, the ARM Core frequency changed to 500 MHz for F-series - In the feature list, changed the DRAM controller frequency - Updated Part Nummbering format - Clarified the Fields table as per Marketing - Sample numbers updated - From the VREG electrical specifications tables, deleted pre-trimming rows and comments - In the HPREG electrical characteristics table, add footnote on maximum Output Current Capacity - In the ULPREG electrical characteristics table, clarified max value of Output voltage @ no load and min value of Output voltage @ full load - In the WBREG electrical characteristics table, clarified max value of Output voltage @ no load and min value of Output voltage @ full load

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Table 79. Revision History (continued)

Rev. No.	Date	Substantial Changes
		- In the LVD electrical specifications table, added typ. values of Upper voltage threshold (value @27oC) and Lower voltage threshold (value @27oC) - In the LVD DIG electrical specifications table, removed pretrimming values and clarified other values - Updated LVD DIG electrical specifications values - Updated LDO_1P1 tables - Updated LDO_2P5 table - Updated Power consumption operating behaviors tables - Updated Absolute maximum ratings table - Removed Temperature Voltage Monitor section to security RM - Updated VideoADC Specifications table
Rev 5	April 2013	Updated pin muxing table with the following changes: - Added MII0 including M AC0.TXDATA[2], MAC0.TXDATA[3], MAC0.RXDATA[2], MAC0.RXDATA[3] , MAC0.TXERR, MAC0.TXCLK, MAC0.RXCLK, MAC0.COL, MAC0.CRS - Following signals muxed on same RMII0 Pins : MII0_MDC, MII0_MDC, MII0_RXD[1], MII0_RXD[0], MII0_RXER, MII0_TXD[1], MII0_TXD[0], MII0_TXEN - Replaced FB_ALE with FB_MUXED_ALE, FB_CS4_b with FB_MUXED_TSIZ0, FB_TSIZ1 with FB_MUXED_TSIZ1, FB_TBST_b with FB_MUXED_TBST_b, FB_BE0_b with FB_MUXED_BE0_b - Removed RCON18,19,20 - Replaced ESAI_SDO2 with ESAI_SDO2/ESAI_SDI3 Replaced ESAI_SDO3 with ESAI_SDO3/ESAI_SDI2 Replaced ESAI_SDI0 with ESAI_SDO5/ESAI_SDI0 Replaced ESAI_SDI1 with ESAU_SDO4/ESAI_SDI1 - CKO1 additionally muxed at PAD40
Rev 5	May 2013	In the Features, minor editorial updates

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VF6xx, VF5xx, VF3xx, Rev8, 11/2014.